



# R820.12

**EN:** 1.4845  
**Type:** 310S



R820.12 is a heat resistant austenitic Cr-Ni-steel with excellent resistance to scaling in continuous service up to 1150°C (2100°F) and if used in intermittent heating and cooling up to 1095°C (2000°F). R820.12 has good resistance to both carburizing and reducing environments and has excellent resistance to oxidizing acids and most common corrosive agents. This grade has better resistance against sigma phase than R823.10/11 (type 314) mainly due to it having a much lower level of silicon content. R820.12 is very slightly sensitive to SO<sub>2</sub> and particularly gases containing H<sub>2</sub>S at temp. over 650°C (1200°F). Typical applications are wire for furnace parts, annealing boxers, heat exchangers, chemical plant equipment and welding wire.

## CHEMICAL COMPOSITION (Nominal) %

C	Si	Mn	Cr	Ni	Mo	N		
0.045	0.80	1.50	24.4	19.3	<0.60	0.050		

PRE: 26 (PRE = Cr + 3.1 x Mo + 25 x N)

Comments:

## PHYSICAL PROPERTIES

Condition: Annealed

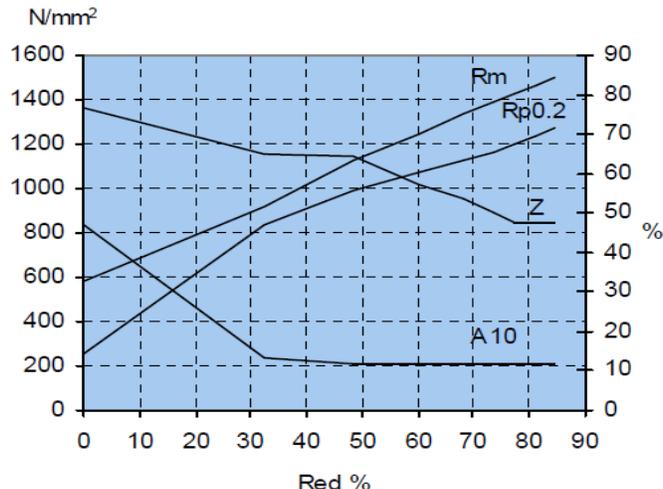
Density	7.9 g / cm <sup>3</sup>
Moduls of elasticity, E	200 000 GPa
Specific heat 0-100°C	500 J / kg°C

## TYPICAL MECHANICAL PROPERTIES

Condition: Annealed

Proof strength	Rp0.2	min. 180 N / mm <sup>2</sup>
Tensile strength	Rm	500-600 N / mm <sup>2</sup>
Elongation	A10	min. 40 %

## DEFORMATION GRAPH



## THERMAL TREATMENT

	°C	°F
Annealing temperature	1050-1150	1920-2100

## MAX. OPERATING TEMPERATURE

	°C	°F
Scaling temp. in air	1150	2100
Oxidizing atm. intermitt. / cont.	1095-1150	2003-2102
Oxidizing sulphurous atm.	850-1000*	1562-1832*
Reducing sulphurous atm.	600-850*	1112-1562*

\*) Max temp. depending on flue gas impurities (S, Na, V)

## THERMAL CONDUCTIVITY

20 °C	12.0 W / mK
100 °C	13.5 W / mK
200 °C	14.5 W / mK
400 °C	17.0 W / mK
600 °C	19.0 W / mK
800 °C	22.5 W / mK

## THERMAL EXPANSION

Thermal expansion per °C x 10<sup>-6</sup> from 20°C to:

200 °C	15.5
400 °C	17.0
600 °C	17.5
800 °C	18.5
1000 °C	19.0

## RESISTIVITY

20 °C	850 μΩmm
100 °C	930 μΩmm
200 °C	1030 μΩmm
400 °C	1220 μΩmm
600 °C	1370 μΩmm
800 °C	1430 μΩmm